Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-065-5568

## **Inclosure Material:** Glass **Overall Length:** Between 0.250 inches and 0.290 inches **Overall Diameter:** Between 0.090 inches and 0.110 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-7 **Mounting Method:** Clip **Features Provided:** Hermetically sealed case Semiconductor Material: Silicon **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average watts **Power Rating Per Characteristic:** 0.250 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0